TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7W53FU, TC7W53FK

2-Channel Multiplexer/Demultiplexer

The TC7W53 is a high speed C^2MOS Analog Multiplexer/ Demultiplexer fabricated with silicon gate C^2MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the C^2MOS low power dissipation. The TC7W53 has a 2 channel configuration.

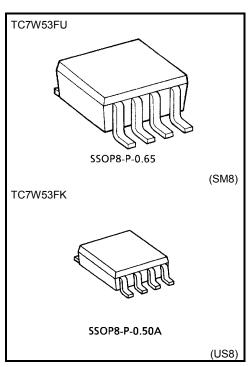
The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ($V_{\rm CC}-V_{\rm EE}$) can then be switched by the small logical amplitude ($V_{\rm CC}-G_{\rm ND}$) control signal.

For example, in the case of $V_{\rm CC}=5$ V, GND=0 V, $V_{\rm EE}=-5$ V, signals between -5 V and +5 V can be switched from the logical circuit with a signal power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuit with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

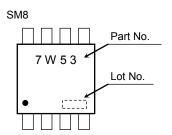
Features

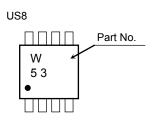
- High speed: $t_{pd} = 15 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$, $V_{EE} = 0 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Low ON resistance: RON = 50Ω (typ.) at VCC-VEE = 9 V
- High degree of linearity: THD = 0.02% (typ.) at V_{CC}-V_{EE} =9 V
- Pin and function compatible with TC4W53



Weight SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)

Marking





Start of commercial production 1997-12

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	–0.5 to 7	V	
Supply voltage range	V _{CC} – V _{EE}	−0.5 to 13	V	
Control input voltage	V _{IN}	-0.5 to $V_{CC} + 0.5$	V	
Switch I/O voltage	V _{I/O}	V_{EE} -0.5 to V_{CC} + 0.5	V	
Control input diode current	Ick	±20	mA	
I/O diode current	I _{IOK}	±20	mA	
Switch through current	Ι _Τ	±25	mA	
DC V _{CC} /GND current	Icc	±25	mA	
Dower discipation	D-	300 (SM8)	mW	
Power dissipation	P _D	200 (US8)		
Storage temperature range	T _{stg}	-65 to 150	°C	
Lead temperature (10 s)	TL	260	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

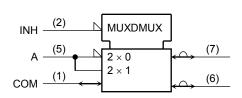
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Truth Table

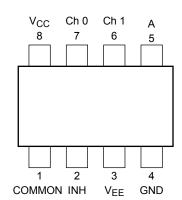
Contro	l Input	On Channel
INH	Α	On Channel
L	L	Ch 0
L	Н	Ch 1
Н	Х	None

X: Don't care

Logic Symbol

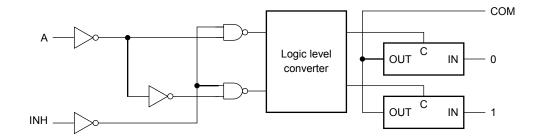


Pin Assignment (top view)





Logic Diagram



Operating Ranges

Characteristics	Symbol	Rating	Unit	
	V _{CC}	2 to 6	_	
Supply voltage	V _{EE}	−6 to 0	V	
	V _{CC} – V _{EE}	2 to 12		
Control input voltage	V _{IN}	0 to V _{CC}	٧	
Switch I/O voltage	V _{I/O}	V _{EE} to V _{CC}	>	
Operating temperature range	T _{opr}	-40 to 85	°C	
		0 to 1000 (V _{CC} = 2.0 V)		
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns	
		0 to 400 (V _{CC} = 6.0 V)		



Electrical Characteristics

DC Electrical Characteristics

Characte	eristics	Symbol	Symbol Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
		- ,		V _{EE} (V)	V _{CC} (V)	Min	Тур.	Max	Min	Max	
			_	2.0	1.5	_	_	1.5	_		
	High level	V _{IHC}	_	_	4.5	3.15	_	_	3.15	_	
Control input				_	6.0	4.2	_	_	4.2	_	V
voltage				_	2.0			0.5		0.5	V
	Low level	V_{ILC}	_	_	4.5		_	1.35		1.35	
				_	6.0			1.8	_	1.8	
			V _{IN} = V _{ILC} or V _{IHC}	GND	4.5		85	180	_	225	
			$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5		55	120	_	150	Ω
			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0		50	100		125	
ON resistance		R _{ON}	ON	GND	2.0		150	_		_	
			V _{IN} = V _{ILC} or V _{IHC}	GND	4.5		70	150	_	190	
			$V_{I/O} = V_{CC}$ or V_{EE} $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5		50	100		125	
				-6.0	6.0		45	80		100	
Difference of C)N		V _{IN} = V _{ILC} or V _{IHC}	GND	4.5		10	30		35	
resistance bety		ΔR_{ON}	$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5		5	12		15	Ω
switches			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0		5	10	_	12	
Input/output lea	akage		$V_{OS} = V_{CC}$ or GND	GND	6.0		_	±60		±600	
current (switch		I _{OFF}	$V_{IS} = GND \text{ to } V_{CC}$ $V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0	_	_	±100	_	±1000	nA
Switch input lea	akage	, v	V _{OS} = V _{CC} or GND	GND	6.0	_	_	±60	_	±600	nA
(switch on outp	out open)	ΊΖ	$I_{IZ} V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0	_	_	±100	_	±1000	I IA
Control input c	urrent	I _{IN}	$V_{IN} = V_{CC}$ or GND	GND	6.0	_	_	±0.1	_	±1.0	μА
Quiocoopt aux	nly ourront	laa		GND	6.0		_	4		40	^
Quiescent supply current	I_{CC} $V_{IN} = V_{CC}$ or GND	-6.0	6.0	_	_	8	_	80	μА		



AC Electrical Characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 6 \text{ ns}$, GND = 0 V)

Characteristics	Characteristics Symbol Test Cor		Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	1001 0011011011	V _{EE} (V)	V _{CC} (V)	Min	Тур.	Max	Min	Max		
			GND	2.0		25	60		75	ns
Phase difference between	φΙ/О		GND	4.5		6	12		15	
input and output	ψι/Ο	_	GND	6.0		5	10		13	
			-4.5	4.5		4			_	
			GND	2.0		50	225		280	
Outrout available times	t _{pZL}	D 4160	GND	4.5		14	45		56	ns
Output enable time	t_{pZH}^{tpCL} $R_L = 1 k\Omega$	$R_L = 1 \text{ K}\Omega$	GND	6.0		12	38		48	
		-4.5	4.5	_	14	_	_	_		
			GND	2.0	_	95	225	_	280	ns
tol:	t _{pLZ}		GND	4.5	_	30	45	_	56	
Output disable time	t _{pHZ}		GND	6.0	_	26	38	_	48	
			-4.5	4.5	_	26	_	_	_	
Control input capacitance	C _{IN}	_	_	_	_	5	10	_	10	pF
Common terminal capacitance	C _{IS}	_	-5.0	5.0	_	11	20	_	20	pF
Switch terminal capacitance	C _{OS}	_	-5.0	5.0	_	7	15	_	15	pF
Feed through capacitance	C _{IOS}		-5.0	5.0		0.75	2		2	pF
Power dissipation capacitance	C _{PD}	(Note)	GND	5.0	_	67	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$



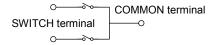
Analog Switch Characteristics (GND = 0 V, Ta = 25°C)

Characteristics	Symbol	Test Condition				V _{CC} (V)	Тур.	Unit	
		V _{IN} = 4.0 Vp-p		-2.25	-2.25	0.025			
Sine wave distortion (T.H.D)			V _{IN} =		-4.5	4.5	0.02	%	
,		IIIV - I KIIZ		11 Vp-p	-6.0	6.0	0.018		
			(Note		-2.25	-2.5	120		
				(Note2)	-2.25	-2.5	95	NAL I-	
Frequency response		Adjust V _{IN} voltage to obtain 0dBm at V Increase F _{IN} until dB Meter reads –3c	-	(Note1)		4.5	190		
(switch ON)	t _{MAX}	$ \begin{array}{c} R_L = 50 \; \Omega, \; C_L = 10 \; pF \\ f_{IN} = 1 \; MHz, \; sine \; wave \end{array} $		(Note2)	-4.5	4.5	150	MHz	
				(Note1)	6.0	6.0	200		
				(Note2)			190		
	_	V _{IN} is centered at (V _{CC} -V _{EE})/2. Adjust	st input t	for 0dBm	-2.25	2.25	-50		
Feed Through attenuation (switch OFF)		$R_L = 600 \ \Omega$, $C_L = 50 \ pF$ $f_{IN} = 1 \ MHz$, sine wave			-4.5	-4.5	-50	dB	
,					-6.0	6.0	-50		
Crosstalk					-2.25	2.25	60		
(control input to signal	_	$R_L = 600~\Omega,~C_L = 50~pF$ $f_{IN} = 1~MHz,~square~wave~(t_r = t_f = 6~ns)$			-4.5	.5 –4.5	140	mV	
output)					-6.0	6.0	200		
Adjust V _{IN} to obtain 0dBm at input				2.25	2.25	-50			
Crosstalk (between any switches)	_	$R_L = 600 \Omega$, $C_L = 50 pF$			-4.5	-4.5 -4.5	-50	dB	
`		f _{IN} = 1 MHz, sine wave			6.0	6.0	-50		

Note: These characteristics are determined by design of device.

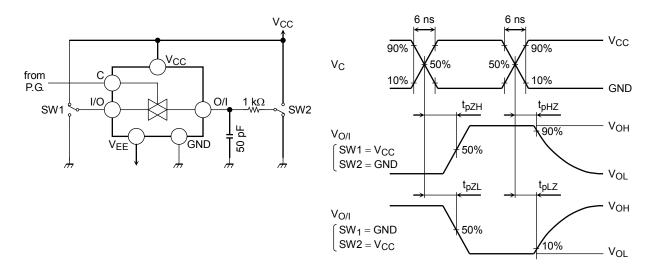
Note 1: Input COMMON terminal, and measure at SWITCH terminal.

Note 2: Input SWITCH terminal, and measure at COMMON terminal.

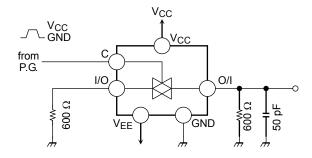


Switching Characteristics Test Circuits

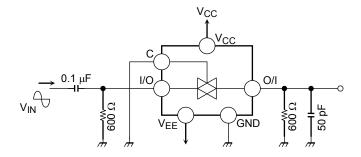
1. t_{pLZ} , t_{pHZ} , t_{pZL} and t_{pZH}



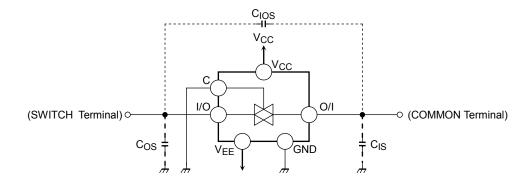
2. Cross Talk (control input-switch output) $f_{IN} = 1$ MHz, duty = 50% and $t_r = t_f = 6$ ns



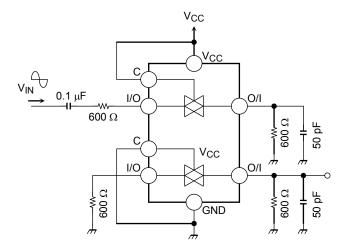
3. Feed Through Attenuation



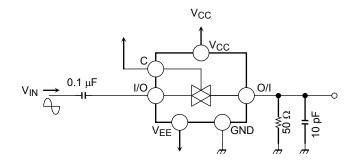
4. CIOS, CIS, COS



5. Cross Talk (between any two switches)

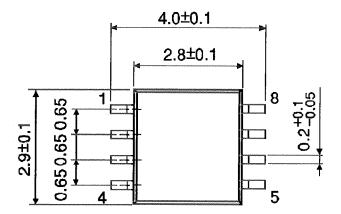


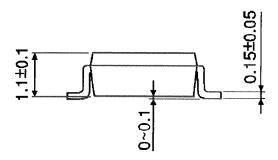
6. Frequency Response (switch ON)



Package Dimensions

SSOP8-P-0.65 Unit: mm



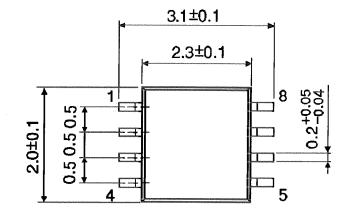


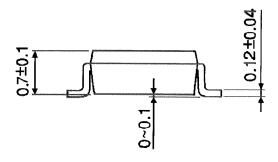
Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A







Weight: 0.01 g (typ.)

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